E lectronic Structure of P aram agnetic $\mathrm{V}_{2} \mathrm{O}_{3}$ : Strongly C orrelated M etallic and M ott In su lating P hase

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#### Abstract

LDA + DMFT, the com putation schem e merging the local density approxi$m$ ation and the dynam icalm ean- eld theory, is em ployed to calculate spectra both below and above the Ferm ienergy and spin and orbitaloccupations in the correlated param agnetic $m$ etallic and M ott insulating phase of $\mathrm{V}_{2} \mathrm{O}_{3}$. The selfconsistent DM FT equations are solved by quantum M onte C arlo sim ulations. R oom tem perature calculations provide direct com parison w ith experim ent. They show a signi cant increase of the quasiparticle height in com parison w ith the results at $1160 \mathrm{~K} . \mathrm{W}$ e also obtain new insights into the nature of the M ottH ubbard transition in $\mathrm{V}_{2} \mathrm{O}_{3}$. Nam ely, it is found to be strikingly di erent from that in the one-band $\mathrm{H} u b b a r d \mathrm{~m}$ odel due to the orbital degrees of freedom. Furtherm ore we resolve the puzzle of the unexpectedly sm all M ott gap in C r-doped $\mathrm{V}_{2} \mathrm{O}_{3}$.


## I. INTRODUCTION

The phase transition between a param agnetic metal and a param agnetic insulator caused by the $C$ oulom $b$ interaction betw een the electrons is referred to as M ottH ubbard $m$ etal-insulator transition. ${ }^{1,2}$ Reliable $m$ icroscopic investigations of this $m$ any-body phenom enon are known to be exceedingly di cult. Indeed, the question conceming the nature of this transition poses one of the fundam ental theoretical problem $s$ in condensed $m$ atter physics. C orrelation-induced $m$ etal-insulator transitions (M IT ) of this type are found, for exam ple, in transition $m$ etal oxides w ith partially lled bands near the Ferm i level. In these system s band theory typically predicts m etallic behavior. The m ost fam ous exam ple is $\mathrm{V}_{2} \mathrm{O}_{3}$ doped w ith $\mathrm{C} r_{i}^{315}$ see Fig . 1. W hile at low tem peratures $\mathrm{V}_{2} \mathrm{O}_{3}$ is an antiferrom agnetic insulator (AFI) w ith m onoclinic crystal sym m etry, the high-tem perature param agnetic phase has a corundum structure. All transitions show $n$ in the phase diagram are of rst order. In the case of the transitions from the high-tem perature, param agnetic phases into the low -tem perature antiferrom agnetic phase this is naturally explained by the fact that the transition is accom panied by a change in crystalsym $m e-$ try. By contrast, the M IT in the param agnetic phase is iso-structural; only the ratio of the $c=a$ axes changes discontinuously. This $m$ ay be taken as an indication for a predom inantly electronic origin of this transition.

To explain an M IT induced by electronic correlations one can either investigate a sim pli ed electronic manybody $m$ odelto understand, at least, som e of the basic features of the M IT , or em ploy $m$ aterial-speci c approaches such as the density functional theory in the local density approxim ation (LDA). C onceming the form er approach, ${ }^{1,3}$ the spin $S=1=2$, half- lled, single-band $H u b-$ bard m odel ${ }^{618}$ is certainly the sim plest possible m odel


F IG. 1: P hase diagram of $\mathrm{V}_{2} \mathrm{O}_{3}$ show ing the M IT as a function of pressure and of doping w ith Cr and T ; data points from $M$ ow han et $a l^{5}$
to be investigated. In particular, the existence of an M IT in the param agnetic phase of the half- led H ubbard m odel had been investigated already in the early work of H ubbard. ${ }^{6,9}$ H ow ever, while the H ubbard I and III approxim ations ${ }^{6,9}$ describe the insulating phase rather well, they do not describe a Ferm i liquid phase on the $m$ etallic side. On the other hand, the G utzw iller approxim ation provides a picture of the break-dow $n$ of the Ferm i
liquid phase as indicated by the collapse of the quasiparticle peak and the sim ultaneous divergence of the effective $m$ ass at a critical value of the $C$ oulom $b$ interaction $U_{c}$ (Brinkm an $R$ ice transition). ${ }^{10} \mathrm{H}$ ow ever, within this fram ew ork one cannot describe the H ubbard bands $w$ hich are essentialboth in the strongly correlated $m$ etallic phase below $U_{C}$ and in the insulating phase above $U_{C}$. $W$ ith these lim itations, the details of the M IT in the $H$ ubbard $m$ odel rem ained unclear, except for the onedim ensional case ${ }^{11}$ which is very particular since it always describes an insulator, i.e., $\mathrm{U}_{\mathrm{C}}=0^{+}$.

D uring the last few years, our understanding of the M IT in the one-band Hubbard m odel has considerably im proved due to the developm ent of dynam ical $m$ eaneld theory (DMFT). ${ }^{12,13} \mathrm{~W}$ thin DMFT the electronic lattioe problem is $m$ apped onto a self-consistent singleim purity A nderson model ${ }^{13}$ This $m$ apping becom es exact in the lim it of in nite coordination number ${ }^{12}$ and allow s one to investigate the dynam ics of correlated lattioe electrons non-perturbatively at all interaction strengths. This is of essential im portance for a problem like the M IT which occurs at a C oulomb interaction com parable to the electronic band-w idth. In particular, DM FT provides a fram ew ork for deriving a coherent picture of the electronic spectrum at allenergy scales, i.e., of the incoherent features at high energies (H ubbard bands), ${ }^{9}$ and the coherent quasiparticle behavior at low energies. ${ }^{7,14}$ At $T=0$, the transition from the $m$ etallic to the insulating state is signaled by a divergence of the e ective $m$ ass and the collapse of the Ferm i liquid quasiparticle peak at the Ferm i energy for C oulomb interaction $\mathrm{U}!\mathrm{U}_{\mathrm{c}} \cdot{ }^{13,15\{17}$ DMFT furthem ore revealed the coexistence of the $m$ etallic and the insulating phase below a critical point at tem perature $\mathrm{T}_{\mathrm{c}}$, such that there is a rst order phase transition in agreem ent $w$ ith the experim entalobservation for $\mathrm{V}_{2} \mathrm{O}_{3}$. To investigate the M IT in $\mathrm{V}_{2} \mathrm{O}_{3}$, R ozenberg et al. ${ }^{18}$ applied DM FT to the one-band H ubbard m odel. The in uence oforbitaldegeneracy was studied by $m$ eans of the tw o- ${ }^{19\{21}$ and three-band ${ }^{20} \mathrm{H}$ ubbard $m$ odel for the sem icircular density of states (D O S) of a B ethe lattice. M ost recently, a detailed analysis ${ }^{22}$ of the conductivity change dem onstrated that, except for a very narrow region directly at the critical point, the critical exponents are of the liquid-gas transition type, in accordance $w$ th a Landau theory for the M ott transition w thin DMFT. 15,23,24

A though the H ubbard m odel is able to explain certain basic features of the M ott H ubbard M IT in $\mathrm{V}_{2} \mathrm{O}_{3}$ and its phase diagram, it cannot explain the physics of that $m$ aterial in any detail. C learly, a realistic theory of $\mathrm{V}_{2} \mathrm{O}_{3} \mathrm{~m}$ ust take into account the com plicated electronic structure of this system. In our previous work, ${ }^{25}$ we therefore applied the LDA + DM FT schem e to study the M IT in param agnetic $\mathrm{V}_{2} \mathrm{O}_{3} \cdot{ }^{26,27} \mathrm{~W}$ th LDA spectra calculated for the crystal structure of $m$ etallic $\mathrm{V}_{2} \mathrm{O}_{3}$ and insulating $\left(\mathrm{V}_{0: 962} \mathrm{C} r_{0: 038}\right)_{2} \mathrm{O}_{3}$ as input for the subsequent three-band DM FT (QMC) calculations, we found an M IT, or rather a shanp crossover, at U 5 eV .

D ue to restrictions in com puter resources, the QM C calculations in Ref. 25 were done at $T=1160 \mathrm{~K}$. Subsequently, extensive QM C sim ulations at tem peratures down to $T \quad 300 \mathrm{~K}$ were perform ed to m ake possible a com parison betw een experim ent and theory at experin entally relevant tem peratures. Those com putations yielded spectra w ith a quasiparticle peak at the Ferm i edge considerably stronger than that at 1160 K and were in contrast to the existing photoem ission $m$ easurem ents. This puzzle was nally resolved by recent im provem ents in photoem ission spectroscopy (PES) experim ents which allow ed one to perform high-energy, bulk sensitive PES, displaying a prom inent peak at $E_{F}$ in essential agreem ent with the LDA + DMFT results. ${ }^{28}$

In this paper, we provide details of our calclations reported in Ref. 28, present LDA + DMFT spectra for $300 \mathrm{~K}, 700 \mathrm{~K}$ and 1160 K both below and above the Ferm iedge, and com pare them to PES and XAS measurem ents. B ased on calculations of spin and orbitaloccupations, we then discuss the properties of the ground state. In particular, the nature of the M IT tums out to be rather distinct from that in a one-band $m$ odel, i.e., we nd that the e ective $m$ ass in the $a_{1 g}$ orbitals does not diverge at the M IT transition.

The paper is organized as follow s: In Section II the LDA band structure, based on the experim ental corundum crystal structure, and the relevance of $V-V$ pairs are discussed. Electronic correlations are taken into account by DM FT as described in Section III. T he resulting LDA + DMFT spectra are presented in Section IV, including a discussion of the dependence on tem perature and the H und's rule exchange coupling. T he pecularities of the M IT in $\mathrm{V}_{2} \mathrm{O}_{3}$ and the di erences to the M IT of the one-band $H$ ubbard $m$ odel are w orked out in Section V. A detailed com parison $w$ ith the experim ental spectra follows in Section VI. A sum m ary and outlook is nally provided in Section VII.

## II. CRYSTALAND ELECTRON IC STRUCTURE

In the param agnetic $m$ etallic phase stoichiom etric $\mathrm{V}_{2} \mathrm{O}_{3}$ crystallizes in the conundum structure, which has a trigonal lattioe and space group R 3c (D ${ }_{3 d}^{6}$ ) w ith lattice constants $a=4: 9515 \mathrm{~A}$ and $\mathrm{c}=14: 003 \mathrm{~A} .{ }^{29}$ Vanadium and oxygen atom s occupy the $W$ ycko positions (12c) and (18e) w ith intemal param eters $z_{V}=0: 34630$ and $x_{0}=0: 31164$, respectively, which deviate $m$ arkedly from the value $1 / 3$ assum ed in an ideal hexagonal arrangem ent. ${ }^{29} \mathrm{~W}$ thin the corundum structure the vanadium atom s are arranged in pairs along the hexagonal c-axis, which can be derived from an ideal chain structure by introducing vacancies at every third site..$^{30}$ The oxygen atom $s$ form distorted octahedra around the vanadium sites. W hile the $V-V$ pair along the hexagonal $C^{-}$ axis shares octahedralfaces, the octahedra are interlinked via edges and comers penpendicular to this axis, ${ }^{29,30}$ see Fig. 2.


F IG . 2: C rystal structure of $\mathrm{V}_{2} \mathrm{O}_{3}$.

In the Cr-doped param agnetic insulating phase the lattice symm etry is preserved, but the crystal structure param eters change slightly. In particular, for $\left(\mathrm{V}_{0: 962} \mathrm{Cr}_{0: 038}\right)_{2} \mathrm{O}_{3}$ the lattice constants am ount to $\mathrm{a}=$ 4:9985A and $c=13: 912 \mathrm{~A}$ and the positional param eters are $\mathrm{z}_{\mathrm{V}}=0: 34870$ and $\mathrm{x}_{\mathrm{O}}=0: 30745$, respectively. ${ }^{29}$ A 11 these changes com bine into a distinct displacem ent pattem: As com pared to the $m$ etallic phase the shared octahedralfaces betw een the $V-V$ pair shrink, while those octahedral faces pointing to the opposite side along the c-axis, i.e., tow ards the aforem entioned vacancies, are enlarged. At the sam e tim e, the vanadium atom $s$ shift aw ay from the shared faces of the $V-V$ pair such that the distances w thin the $V-V$ pair increase upon $C r$-doping, even though the c-axis lattice constant decreases. T he increased a-axis lattice constant directly leads to enhanced vanadium distances w ithin the ab-plane. A s a net result, all nearest-neighbor vanadium distances are en larged for insulating $\left(\mathrm{V}_{0: 962} \mathrm{Cr}_{0}: 038\right)_{2} \mathrm{O}_{3}$. H ence, we expect a reduction of the bandw idth especially of the $t_{2 g}$-derived bands. From a com parison of pure and doped $\mathrm{V}_{2} \mathrm{O}_{3}$ as well as $\mathrm{Cr}_{2} \mathrm{O}_{3}$, D emier ${ }^{29}$ conchuded that the m etallic properties are intim ately connected $w$ ith the vanadium hopping w ithin the ab-plane rather than $w$ ith hopping processes betw een the $V-V$ pairs along the $z$-axis.

In a nst step LDA band structure calculations ${ }^{31,32}$ were perform ed, which used the augm ented spherical wave (A SW ) m ethod. ${ }^{33,34} \mathrm{~F}$ igs. 3,5,6, and 7 show these bandstructures along selected high sym m etry lines (Fig. 4) w ithin the rst B rillouin zone of the hexagonal lattice and the densities of state (DOS) for $\mathrm{V}_{2} \mathrm{O}_{3}$ and ( $\mathrm{V}_{0}$ :962 $\left.\mathrm{Cr}_{0}: 038\right)_{2} \mathrm{O}_{3}$, respectively.

In total our results are in good agreem ent w ith those published by $M$ attheiss. ${ }^{30}$ In particular, while the $O$ 2p derived bands show up in the range betw een -9 and -4 eV , the V 3d dom inated states fall, due to the octahedral surrounding w ith oxygen, into tw o groups of bands: $t_{2 g}$ and $e_{g} \cdot W$ ith this separation, the $e_{g}$ bandswillbe em pty and the $t_{2 g}$ bands partially led $w$ ith two electrons per V ion.

D ue to the lower trigonal lattioe sym metry the $t_{2 g}$ states are further split into doubly and singly degenerate $e_{g}$ and $a_{1 g}$ states, see $F$ igs. 5,7 and the schem e Fig. 8. The value of this splytting ( $0: 3 \mathrm{eV}$ for the


FIG. 3: Electronic bands of $\mathrm{V}_{2} \mathrm{O}_{3}$ along selected symm etry lines w ithin the rst B rillouin zone of the hexagonal lattice, Fig. 4. The width of the bars given for each band indicates the contribution from the $\mathrm{a}_{1 \mathrm{~g}}$ orbitals.


F IG . 4: First B rillouin zone of the hexagonal lattice.
centers of gravity) is much sm aller than the $t_{2 g}$ bandwidth ( 2 eV ). H ow ever, as the value of the C oulom b interaction param eter $U(U>4 e V)$ is larger than the bandw idth, this sm all trigonal splitting strongly deter$m$ ines the orbitalground state of the $V$-ion obtained from LDA + D M FT calculations, as will be shown below. To highlight the di erence betw een $e_{g}$ and $a_{1 g}$ states, we append to each band at each $k$ point a bar in $F$ ig. 3, whose length is a m easure for the contribution from the $\mathrm{a}_{1 \mathrm{~g}}$ orbitals to the respective w ave function.

The changes on going to $\left(\mathrm{V}_{0: 962} \mathrm{Cr}_{0: 038}\right)_{2} \mathrm{O}_{3}$ are stated easily: In Figs. 6 and 7, we observe a narrow ing of the $t_{2 g}$ and $e_{g}$ bands of 0.2 and 0.1 eV , respectively, as well as a slight dow nshift of the centers of gravity of the $e_{g}$ bands. H ow ever, the insulating band gap expected for a calculation $w$ ith the insulating crystal structure is $m$ issing.

A s already m entioned a peculiarity of the corundum crystal structure are the c-axis $V-V$ pairs. Long ago A llen ${ }^{35}$ em phasized the im portance of the intra-pair interactions for intenpreting spectroscopic properties of


F IG.5: Total and partial densities of states (D O S) of $\mathrm{V}_{2} \mathrm{O}_{3}$ per unit cell.


F IG . 6: E lectronic bands of $\left(\mathrm{V}_{0: 962} \mathrm{C} r_{0: 038}\right)_{2} \mathrm{O}_{3}$.
$\mathrm{V}_{2} \mathrm{O}_{3}$ and its solid solution w ith $\mathrm{Cr}_{2} \mathrm{O}_{3}$. Since the $\mathrm{a}_{1 \mathrm{~g}}$ orbitals are directed along the c-axis, these onbitals are the ones which $m$ ediate a strong hybridization betw een $V-V$ pairs. $T$ his hybridization for the $V-V$ pair led $C$ astellani et $\mathrm{al}^{36}$ to a model (see Fig. 8) where two of the four electrons per $V-V$ pair occupy a bonding $m$ olecular orbital form ed by $a_{1 g}$ orbitals, leaving tw o electrons (one per site) in a partially lled tw ofold-degenerate $e_{g}$ band. That results in a spin $\frac{1}{2}$ orbitally degenerate state per $V$ ion w th com plicated orbitaland spin ordering pattem explaining the unusualproperties of the low -tem perature antiferrom agnetic phase.

Indeed, $F$ igs. 3 and 5 show som e splitting of the $\mathrm{a}_{1 \mathrm{~g}}$ bands, in particular, betw een the $M$ and the $K$ point of the bandstructure, as one would expect from the form ation of a chem icalbond. But, the situation is far more com plicated than a sim ple chem icalbonding of the $\mathrm{a}_{1 \mathrm{~g}}$ band into a bonding and an anti-bonding band: There is som e additional spectral weight near $\mathrm{E}_{\mathrm{F}}$ (e.g., in the vicinity of the point). M oreover, there is not even a low -lying \bonding" $a_{1 g}$ band in parts of the $B$ rillouin


FIG. 7: Total and partial densities of states (DOS) of $\left(\mathrm{V}_{0: 962} \mathrm{Cr}_{0} 0038\right)_{2} \mathrm{O}_{3}$ per unit cell.


FIG. 8: Left and right: splitting of the $t_{1 g}$ orbitals in the corundum crystalstructure. M iddle: Form ation of a chem ical bond for a single $\mathrm{V}-\mathrm{V}$ pair along the c-axis.
zone (e.g. betw een the $H$ and A point).
The C astellaniet al. model ${ }^{36}$ w as challenged by Park et $a l^{37}$ B ased on the polarization dependence of $x$-ray absorption experim ents they cam e to the conclusion that the $\mathrm{V}^{3+}$ ion is in a spin-1 state. They also dem onstrated that the orbital ground state of the ion is predom inantly $e_{g} e_{g} w$ th a sm all adm ixture of $e_{g} a_{1 g}$ con $g-$ urations. This was later supported by LDA $+U$ calculations of E zhov et al ${ }^{38}$ where a spin-1 ground state with $a e_{g} e_{g}$ onbital con guration was obtained.

N evertheless, the picture where the strongest hybridization param eter in $\mathrm{V}_{2} \mathrm{O}_{3}$ is the $\mathrm{a}_{1 g} \quad a_{1 g}$ hopping w thin the $\mathrm{V}-\mathrm{V}$ pair, w th all other hybridizations being $\mathrm{m} u \mathrm{ch}^{\mathrm{sm}}$ aller, is still popular. M any theoretical studies ofth is $m$ aterialstart with a (as good aspossible) solution for the $V-V$ pair and consider the inter-pair interactions as a perturbation. ${ }^{39141} \mathrm{~A}$ ll these m odel calculations w ere based on the values of hopping param eters obtained by least-square $t$ of LDA bands to a model Ham iltonian w ith nearest-neighbor hopping. Recently this problem was reexam ined by El mov et $\mathrm{al}^{42} \mathrm{who}$ found that the value of the $\mathrm{a}_{1 \mathrm{~g}} \quad \mathrm{a}_{1 \mathrm{~g}}$ hopping in the $\mathrm{V}-\mathrm{V}$ pair is signi cantly reduced if next-nearest neighbor hoppings (w hich were found to be signi cant) are taken into account in the $t$ to a model Ham iltonian. Hence, one cannot consider inter-pair hoppings as a $m$ ere perturbation as it $w$ as
taken for granted for a long tim e.

## III. IN CLUDING ELECTRON IC CORRELATIONSVIA DMFT

The LDA band structure of the previous section clearly fails to describe $\left(V_{1} \times C r_{x}\right)_{2} \mathrm{O}_{3}$. In particular, the chrom ium doped com pound $\left(\mathrm{V}_{0: 962} \mathrm{Cr}_{0: 038}\right)_{2} \mathrm{O}_{3}$ is an insulator whereas LDA predicts $m$ etallic behavior. $T$ he reason for this failure is that LDA deals $w$ th electronic correlations only very rudim entarily, nam ely, the dependence of the LDA exchange-correlation energy on the electron density is given by perturbative or quantum $M$ onte-C arlo calculations for jellium, ${ }^{43,44}$ which is a weakly correlated system. To overcom e this shortcom ing, we supplem ent the LDA band structure by the the $m$ ost im portant C oulom b interaction term $s$, i.e., the local C oulom b repulsion $U$ and the localH und's rule exchange $J$. The localC oulom b repulsion $U$ gives rise to a genuine e ect ofelectronic correlations, the M ott $H$ ubbard $m$ etal insulator transition. ${ }^{13,15\{17,23,24,45}$ Ifthe LD A bandw idth is considerably larger than the localC oulom b interaction, the LDA results are slightly $m$ odi ed but the system re$m$ ains a $m$ etal. If the LDA bandw idth is $m u c h ~ s m ~ a l l e r ~$ than the local C oulomb interaction one has essentially the atom ic problem where it costs an energy of about U to add an electron and the system is an insulator. In between, the $M$ ott $H$ ubbard $m$ etal insulator transition occursw ith $\mathrm{V}_{2} \mathrm{O}_{3}$ being on the $m$ etallic side $w$ hereas $\left(\mathrm{V}_{0: 962} \mathrm{C} \mathrm{r}_{0}: 038\right)_{2} \mathrm{O}_{3}$, which has a $0.1-0.2 \mathrm{eV}$ sm aller bandw idth, is on the insulating side.

Interpreting the LD A band structure as a one-particle H am iltonian $\hat{H}_{\text {LD A }}^{0}$ and supplem enting it with the local C oulom b interactions gives rise to the $m$ ultitband $m$ anybody H am iltonian ${ }^{46}$

Here, $i$ denotes the lattice site and $\hat{\mathrm{r}}_{\mathrm{im}}$ is the operator for the occupation of the $t_{2 g}$ orbital $m$ with spin

2 f ";\#g. The interaction param eters are related by $\mathrm{V}=\mathrm{U} \quad 2 \mathrm{~J}$ which is a consequence of orbital rotational sym $m$ etry. This holds exactly for degenerate onbitals and is a good approxim ation in our case where the $t_{2 g}$ bands have sim ilar centers of gravity and bandw idths. As in the local spin density approxim ation (LSDA), the spin-
ip term of the exchange interaction is not taken into account in Eq. (1). T he consequences of this approxim ation for states in the vicinity of the Ferm ienergy do not seem to be large as com parative calculations using the non-crossing approxim ation w ithin DMFT show. ${ }^{47}$ Furtherm ore, a pair hopping term proportional to $J$ is neglected since it requires that one orbital is entirely em pty while another is entirely full which is a rare situation in the solid state and corresponds to highly excited states. For the H und's rule coupling $J$ we take the constrained

LDA value $J=0: 93 \mathrm{eV} \cdot{ }^{48} \mathrm{U}$ nfortunately, such an ab initio calculation is not feasible for the C oulomb repulsion $U$ since $U$ depends sensitively on screening which leads to uncertainties of about $0.5 \mathrm{eV} .{ }^{49}$ For our present purposes this uncertainty is too large since $\mathrm{V}_{2} \mathrm{O}_{3}$ is on the verge of a $M$ ott + ubbard $m$ etal-insulator transition, and, thus, sm all changes of $U$ have drastic e ects. In particular, due to the sm alldi erences in the LD A band structure it is unlikely that for a $U$ value calculated by constrained LDA, $\mathrm{V}_{2} \mathrm{O}_{3}$ is m etallic whereas $\left(\mathrm{V}_{0}: 962 \mathrm{C} r_{0}: 038\right)_{2} \mathrm{O}_{3}$ is insulating. Therefore, we adjust $U$ in such a way as to $m$ ake sure that these two system $s$ are $m$ etallic and insulating, respectively. A posteriori, we will com pare the adjusted value w th those calculated by constraint LD A calculations and those extracted from the experim ent.

So far, we did not specify $\hat{H}_{\text {LD A }}^{0}$. In principle, it should contain the valence orbitals, i.e., the oxygen $2 p$ orbitals and the ve vanadium 3d onbitals per atom and, $m$ aybe, som e additionals orbitals. H ow ever, for $\mathrm{V}_{2} \mathrm{O}_{3}$ we are in the fortunate situation that the three $t_{2 g}$ bands at the Ferm ienergy are well separated from the other orbitals, see Fig. 7. Therefore, it is possible to restrict ourselves to the three $t_{2 g}$ bands at the Ferm i energy which are $m$ ade up of the corresponding atom ic vanadium 3d orbitals $w$ th som e adm ixtures of oxygen p orbitals. In the case of three degenerate $t_{2 g}$ orbitals, which is close to our situation where bandw idths and centers of gravily of the $a_{1 g}$ and the doubly-degenerate $e_{g}$ band are very sim ilar, the $k$-integrated $D$ yson equation sim pli es to becom e an integral over the D O $S^{27}$

$$
\begin{equation*}
G_{m}(!)=\mathrm{Z}_{\mathrm{m}}^{\mathrm{Z}} \frac{\mathrm{~N}_{\mathrm{m}}^{0}()}{!+\quad}: \tag{2}
\end{equation*}
$$

Here $G_{m}(!), m(!)$, and $N_{m}^{0}()^{50}$ are the $G$ reen function, selfenergy, and LD A density of states, respectively, for the $t_{2 g}$ orbitalm. In principle, $N_{m}^{0}()$ should contain a double counting correction, which takes into account that part of the localC oulom b interaction already included in the LD A. H ow ever, this correction results in the sam e effect for all three orbitals and, hence, only translates into a simple shiff of the chem icalpotential. Thism akes the issue of how to calculate the double counting correction irrelevant for the present purposes. The (shifted) has to be controlled according to the vanadium valency, i.e., in such a way that there are two electrons in the three bands at the Ferm ienergy.

W thin DMFT the $k$-integrated Dyson equation (2) has to be solved self-consistently together with a one-site ( $m$ ean eld) problem which is equivalent to an A nderson im purity $m$ odelw ith hybridization $m\left({ }^{\circ}\right)$ ful lling ${ }^{13}$

$$
\begin{equation*}
\left[G_{m}(!)\right]^{1}+{ }_{m}(!)=!+\quad Z_{1}^{Z_{1}} d!^{0} \frac{m^{\left(!!^{0}\right.}}{!!^{0}}: \tag{3}
\end{equation*}
$$

The self-consistent solution of the A nderson im purity model given by (3) together w th the Dyson equation (2) allows for a realistic investigation of $m$ aterials with strongly correlated electrons. At sm all values of $U$ this procedure typically yields a spectrum
with a central quasiparticle resonance at the Ferm ienergy and two incoherent Hubbard side bands, while at larger values of $U$ the quasiparticle resonance disappears and a m etal-insulator transition occurs. ${ }^{12} \mathrm{~T}$ his approach has been successfiully applied to a num ber of transition m etal-oxides, ${ }^{49,51}$ transition m etals, ${ }^{52}$ and elem ental Pu and $\mathrm{Ce} .{ }^{53}$ For m ore details and an introduction to the LDA + DMFT approach we refer the reader to Ref. 27.

In the present paper, we solve the multi-band A nderson im purity m odel by QMC, ${ }^{54}$ where by $m$ eans of the Trotter discretization and H ubbard-Stratonovich transform ations the interacting A nderson im purity $m$ odel is $m$ apped to a sum of non-interacting problem $s$, the sum being perform ed by the $M$ onte-C arlo technique. W e em ploy a Trotter discretization of $=0: 25 \mathrm{eV}{ }^{1}$ unless noted otherw ise and follow Ref. 55 for the Fourier transform ation betw een $M$ atsubara frequencies and im aginary tim e . To obtain the physically relevant spectral fiunction we analytically continue the $G$ reen function from $M$ atsubara frequencies to real frequencies by $m$ eans of the $m$ axim um entropy $m$ ethod. ${ }^{56} \mathrm{~T}$ he QM C has the advantage of being num erically exact while the $m$ ain disadvantage is that it is restricted to higher tem peratures. $T$ he room tem perature calculations of this paper were com putationally very expensive, requiring about 200000 hours CPU tim e on the H itachiSR 8000 F1 at the Leibnitz R echenzentrum M unich. For the im plem entation of QMC in the context of LDA + DMFT, including ow diagram s, see also Ref. 27.

## IV. LDA + D M T SPECTRA

U sing the crystal structure of param agnetic $m$ etallic (PM) $\mathrm{V}_{2} \mathrm{O}_{3}$ and param agnetic insulating (PI) $\left(\mathrm{V}_{0: 962} \mathrm{C} r_{0: 038}\right)_{2} \mathrm{O}_{3}$, respectively, as input, we perform ed LDA + DMFT (QMC) calculations with one $a_{1 g}$ and two degenerate $e_{g}$ bands. $T$ he results for the spectra of the $t_{2 g}$ bands are shown in Fig. 9. At $U=4: 5 \mathrm{eV}$ both crystal structures lead to spectra show ing $m$ etallic behavior, w th a lower H ubbard band at about 1 eV , an upper H ubbard band at 4 eV and a quasiparticle peak at the Ferm i edge $(0 \mathrm{eV})$. The peak at about 1 eV is split from the upper $t_{2 g} H$ ubbard bands due to $H$ und's rule exchange as we w ill discuss below .

By contrast, at $U=5: 5 \mathrm{eV}$, both crystal structures lead to spectra show ing nearly insulating behavior. T he low er H ubbard band is strongly enhanced w hereas at the Ferm i edge, a pseudo-gap is form ed. Above the Ferm i energy, only sm all changes of the two-peak structure are visible.

A pparently, qualitatively di erent spectra for the two crystal structures require an interm ediate value of $U$. $T$ his is indeed observed at $U=5: 0 \mathrm{eV}: \mathrm{W}$ hereas pure $\mathrm{V}_{2} \mathrm{O}_{3}$ now show s a small peak at the Ferm i edge (a residue of the quasiparticle peak obtained at $U=4: 5 \mathrm{eV}$ ) and is therefore m etallic, the Cr-doped system exhibits a pronounced $m$ inimum in the spectrum implying that


FIG. 9: LDA + DMFT (QMC) spectra for param agnetic insulating (P I) ( $\left.\mathrm{V}_{0: 962} \mathrm{Cr}_{0}: 038\right)_{2} \mathrm{O}_{3}$ and metallic (PM) $\mathrm{V}_{2} \mathrm{O}_{3}$ at $\mathrm{U}=4: 5,5,5: 5 \mathrm{eV}$, and $\mathrm{T}=1160 \mathrm{~K}$.
it is nearly insulating. D ue to the high tem perature of $\mathrm{T}=0: 1 \mathrm{eV} \quad 1160 \mathrm{~K}$ of the QMC simulations one only observes a sm ooth crossover betw een the tw o phases w ith a $m$ etal-like and insulator-like behavior of the respective curves instead of a sharp $m$ etal-insulator transition as would be expected for tem peratures below the critical point (i.e., for $T<400 \mathrm{~K}$ in the experim ent). The value of the critical interaction of $5: 0 \mathrm{eV}$ is in accordance w ith constrained LDA calculations by Solovyev et $\mathrm{al}^{48}$ who analyzed the charging energy betw een di- and trivalent vanadium ions in an octahedral oxygen environm ent for $\mathrm{LaVO}_{3}$, obtaining a $U$ value for the $t_{2 g}$ orbitals which is only slightly sm aller than 5 eV . Sim ilar $U$ values of 45 eV were obtained by tting spectroscopy data for vanadium oxides to m odel calculations. ${ }^{57}$

Not only the overall $t_{2 g}$ DOS but also the bandresolved spectra of the $a_{1 g}$ and $e_{g}$ bands provide valuable insight. In F ig. 10, the $\mathrm{a}_{1 \mathrm{~g}}$ and one of the tw o degenerate $e_{g}$ spectra are show $n$ at $U=5: 5 \mathrm{eV}$. The basic features of the spectrum can be understood as follow s: W ew ill show in the next section that the predom inant local con guration has tw o spin-aligned electrons in the $e_{g}$ onbitals, i.e., $a e_{g} e_{g}$ spin-1 con guration, $w$ ith som e adm ixture of $a_{1 g} e_{g}$ spin-1 con gurations. Since there are $m$ ore $e_{g}$ than $a_{1 g}$ electrons, let us for a $m$ om ent disregard the $a_{1 g} e_{g}$ con gurations. The low er $H$ ubbard band at about
$1: 5 \mathrm{eV}$ indicates the rem oval of an $\mathrm{e}_{\mathrm{g}}$ electron from the


FIG. 10: LDA + D M FT (Q M C) spectrum for param agnetic insulating ( $\left.\mathrm{V}_{0: 962} \mathrm{Cr}_{0}: 038\right)_{2} \mathrm{O}_{3}$ (P I) for $\mathrm{U}=5: 5 \mathrm{eV} ; \mathrm{T}=1160 \mathrm{~K}$.
predom inantly $e_{g} e_{g}$ spin-1 con gurations. In an atom ic picture (which is a reasonable starting point for the insulating phase) this $\mathrm{e}_{\mathrm{g}} \mathrm{e}_{\mathrm{g}}!\mathrm{e}_{\mathrm{g}}$ transition leads to an energy gain of $\mathrm{V} \quad \mathrm{J} \quad 1: 5 \mathrm{eV}$ (the approxim ate position of the low er H ubbard band). On the other hand, the upper $e_{g} H$ ubbard band describes the $e_{g} e_{g}!e_{g} e_{g} e_{g}$ transitions. Since the spin-alignm ent is lost this transition costs an energy $\mathrm{U}+\mathrm{V} \quad=\mathrm{U}+\mathrm{J}+(\mathrm{V} \quad \mathrm{J} \quad$ ) 4:4 eV , which roughly agrees w ith the position of the upper H ubbard band. On the other hand, adding an $\mathrm{a}_{1 \mathrm{~g}}$ electron costs $2 \mathrm{~V} \quad 2: 6 \mathrm{eV}$ or $2 \mathrm{~V} 2 \mathrm{~J} 0: 7 \mathrm{eV}$, depending on whether this electron is spin aligned or not. $T$ his $H$ und's rule splitting results in the two-peak structure of the upper $\mathrm{a}_{1 \mathrm{~g}} \mathrm{H}$ ubbard band in F ig. 10. Since there are also $a_{1 g} e_{g}$ spin-1 con gurations, one has som e m odi cations of this picture, in particular, there is also a splltting of the upper $e_{g}$ band, resulting in a sm all peak at $U \quad 0: 5 \mathrm{eV}$ due to $\mathrm{a}_{1 g} \mathrm{e}_{\mathrm{g}}!\mathrm{a}_{1 \mathrm{~g}} \mathrm{e}_{\mathrm{g}} \mathrm{e}_{\mathrm{g}}$ transitions. A sa consequence of the splitting of the upper $H$ ubbard band into a two-peak structure, leading to a peak at about $0: 5 \mathrm{eV}$ above the Ferm iedge, the gap in the insulating phase is very sm all, m uch sm aller than $V \quad 3 \mathrm{eV}$ which would be expected in a one-band $H$ ubbard $m$ odel. $T$ his also explains the puzzle in the attem pt to $m$ odel the optical gap w ith a one-band H ubbard $m$ odel ${ }^{18}$ : tting to the sm allexperim entalgap one is led to an unrealistically sm allC oulom b repulsion of about 1 eV and a bandw idth of less than 0.5 eV .

To study the $m$ etal-insulator transition at experim entally relevant tem peratures, we perform ed calculations at $T=700 \mathrm{~K}$ and $\mathrm{T}=300 \mathrm{~K}$. Since the computational e ort is proportional to $T^{3}$, those low tem perature calculations were com putationally very expensive. Fig. 11 shows the results of our calculations at $\mathrm{T}=1160 \mathrm{~K}$, $\mathrm{T}=700 \mathrm{~K}$, and $\mathrm{T}=300 \mathrm{~K}$ for m etallic $\mathrm{V}_{2} \mathrm{O}_{3}$ and for insulating $\left(\mathrm{V}_{0: 962} \mathrm{C} r_{0: 038}\right)_{2} \mathrm{O}_{3}$. In the m etallic phase, the incoherent features are hardly a ected when the tem perature is changed, whereas the quasiparticle peak becom es sharper and $m$ ore pronounced at low er tem peratures. This behavior also occurs in the A nderson im pu-
rity $m$ odel ${ }^{58}$ and has its origin in the sm oothing of the A brikosov-Suhl quasiparticle resonance at tem peratures larger than the K ondo tem perature. H ow ever, in contrast to the A nderson im purity $m$ odel this sm oothing occurs at considerably low er tem peratures which is apparently an e ect of the DM FT self-consistency cycle.


FIG. 11: LDA + D MFT (Q M C) spectra for param agnetic insulating ( $\left.\mathrm{V}_{0: 962} \mathrm{Cr}_{0}: 038\right)_{2} \mathrm{O}_{3}$ and m etallic $\mathrm{V}_{2} \mathrm{O}_{3}$ at $\mathrm{U}=5 \mathrm{eV}$.

To study the possible e ect of a sm aller H und's rule coupling $J$, we perform ed additional calculations for a reduced value of $J=0: 7 \mathrm{eV}$, keeping V nearly constant. The results in Fig. 12 show that the positions of the upper $H$ ubbard bands are signi cantly shifted towards low er energies while the spectra below the Ferm i energy are hardly a ected. This suggests that the physical properies do not change much. Indeed, we nd, for exam ple, that the spin-1 state hardly changes when the H und's exchange is reduced. Even at values as low as $J=0: 5 \mathrm{eV}$ the localm om ent stays alm ost $m$ axim al, i.e., $\mathrm{mm}{ }_{z}^{2} i=3: 85$ at $\mathrm{J}=0: 5 \mathrm{eV}$, im plying that unrealistically sm all values of $J$ are required for the $C$ astellani et al ${ }^{36}$ picture to hold. ${ }^{59}$
V. CHANGESACROSSTHEMOTTHUBBARD TRANSIT ION
A. Localm agnetic $m$ om ent and orbital occupation

The spin and orbital degrees of freedom play an im portant role in the param agnetic phase of $\mathrm{V}_{2} \mathrm{O}_{3}$ and in the changes occurring across the M IT. For exam ple, we nd the squared localm agnetic $m$ om ent $\mathrm{m}_{\mathrm{z}}^{2}=$


FIG.12: Com parison of the LDA + D M FT (QMC) $\mathrm{V}_{2} \mathrm{O}_{3}$ spectra at tw o strengths of the exchange interaction: $\mathrm{J}=0: 93 \mathrm{eV}$ (as obtained from constrained LDA), $\mathrm{U}=5: 0 \mathrm{eV}, \mathrm{V}=$ $3: 14 \mathrm{eV}$, and $J=0: 7 \mathrm{eV}, \mathrm{U}=4: 5 \mathrm{eV}, \mathrm{V}=3: 1 \mathrm{eV}$.

D P E
${ }^{\mathrm{P}} \mathrm{m}_{\mathrm{m}}\left[\begin{array}{ll}{\left[\hat{\Lambda}_{\mathrm{m}} "\right.} & \left.\left.\hat{\mathrm{A}}_{\mathrm{m}} \#\right]\right)^{2}\end{array}\right.$ to have a value of $\mathrm{m}_{\mathrm{z}}^{2} \quad 4$, unaf fected by the M IT, see Fig. 13. T his value corresponds to tw o spin-aligned electrons in the $\left(a_{1 g}, e_{g 1}, e_{g 2}\right)$ orbitals and therefore to a spin-1 state in the $M$ ott $H$ ubbard transition regim e in good agreem ent w ith polarization dependent $x$-ray absonption $m$ easurem ents of $P$ ark et $a l^{37}$ It also agrees $w$ ith $m$ easurem ents of the high tem perature susceptibility which give the value of eff $=2: 66$ в for thee ectivem agneticm om ent. ${ }^{60} \mathrm{~T}$ h is is close to the ideal $S=1$ value eff $=2: 83$ в. $N$ ote that when $U$ is reduced to $U<3$, the $H$ und's rule coupling $J$ needs to be reduced as well to avoid an unphysical attractive C oulom b interaction (nam ely, a C oulom b energy U 3J $<0$ would otherw ise be gained when a spin-aligned electron is added to a singly occupied site). It is this reduction of $J$ which nally leads to a sm aller local squared $m$ agnetic $m$ om ent. O ur results of a spin state which is essentially una ected by the M IT is in stark contrast to results for the oneband $H$ ubbard $m$ odel where $m_{z}^{2}$ changes strongly at the M IT ${ }^{13}$ (in fact, this quantity had even been used as an indicator for the M IT ).

T he orbitaloccupation ( $F$ ig. 13) obtained by us clearly rules out a $a_{1 g}$ singlet since this would correspond to $\mathrm{n}_{\mathrm{a}_{1 \mathrm{~g}}}=1, \mathrm{n}_{\mathrm{e}_{\mathrm{g}}}=1$. Therefore our results contradict the $m$ odel of $C$ astellani et $a l^{36}$ who proposed the for$m$ ation of an $a_{1 g}$ singlet and hence a spin-1/2 state. At all $U$-values we nd predom inantly occupied $e_{g}$ orbitals, but w ith a signi cant adm ixture of $a_{1 g}$ orbitals (see Fig. 13). On the basis of an analysis of their linear dichroism data $P$ ark et $a l^{37}$ concluded that the ratio of the con gurations ( $e_{\mathrm{g}} ; \mathrm{e}_{\mathrm{g}}$ ) and ( $\left(\mathrm{e}_{\mathrm{g}} ; \mathrm{a}_{1 \mathrm{~g}}\right)$ is equal to $1: 1$ for the param agnetic $m$ etallic phase (PM) and 3:2 for the param agnetic insulating phase (P I). T his corresponds to an electron occupation of the ( $\mathrm{a}_{1 \mathrm{~g}}, \mathrm{e}_{\mathrm{g} 1}, \mathrm{e}_{\mathrm{g} 2}$ ) orbitals of ( $0.4,0.8,0.8$ ) for the P I phase and ( $0.5,0.75,0.75$ ) for the $P M$ phase. At $T=1160 K$ we nd for the PI phase


FIG. 13: a) Spin, and b) orbital occupation vs. C oulom b interaction $U$ for $m$ etallic $\mathrm{V}_{2} \mathrm{O}_{3}$.
("insulating" crystal structure and $U=5: 0 \mathrm{eV}$ ) occupations of ( $0.28,0.86,0.86$ ), while for the $m$ etallic phase ("m etallic" crystal structure and $U=5: 0 \mathrm{eV}$ ) we obtain (0.37,0.815,0.815). W hile our results give a sm aller value for the adm ixture of $a_{1 g}$ orbitals (even $m$ ore so at $T=300 \mathrm{~K}$ ), the tendency for the decrease of th is value at the transition to the insulating state is well reproduced. Fig .13 also show $s$ that in the im m ediate vicinity of the M ott transition the orbitaloccupation has a considerable tem perature dependenœ, w ith even few er electrons in the $a_{1 g}$ orbitals at low er tem peratures.

Further experim entalevidence for a $\left(e_{g} ; e_{g}\right)$ con guration in the ground state of the $\mathrm{V}^{+3}$ ions in $\mathrm{V}_{2} \mathrm{O}_{3}$ com es from B rown et $a l^{61} T$ hey $m$ easured the spatial distribution of the eld-induced $m$ agnetization in param agnetic $\mathrm{V}_{2} \mathrm{O}_{3}$ by polarized neutron di raction. Their results show that the $m$ om ent induced on the $V$ atom $s$ is alm ost entirely due to the electrons in the doubly degenerate $e_{g}$ orbitals $w$ ith only a m inor contribution from the $\mathrm{a}_{1 \mathrm{~g}}$ orbital. For the antiferrom agnetic insulating phase of $\mathrm{V}_{2} \mathrm{O}_{3}$, calculations of the electron ic structure by LD A + U also yielded a spin-1 ground state for the $\mathrm{V}^{3+}$ ion and a ( $e_{g} ; \mathrm{e}_{\mathrm{g}}$ ) onbitalcon guration. ${ }^{38}$

The origin for the ground state orbital con guration discussed above is easily understood from the LDA DOS ( F ig. 5) where the center of gravity of the $\mathrm{a}_{1 g}$ orbital is 0.3 eV higher in energy than the corresponding value for $e_{g}$ orbitals. This shiff together with the asym m etry of the DOS leads to an LDA occupation of about 0.55 for the $a_{1 g}$ and 0.72 for each of the $e_{g}$ bands. The occupation of $e_{g}$ orbitals is further enhanced in the strongly correlated $m$ etallic regim e and, in particular, in the insulating phase where the Coulomb interaction value ( $\mathrm{U}>5 \mathrm{eV}$ ) is signi cantly larger than the bandw idth (w 2 eV ).
B. Q uasiparticle renorm alization and spectral w eight at the Ferm i level

To study the M IT in detail we have calculated the quasiparticle weight $Z$ by tting a third order polynom inal to the im aginary part of the QMC selfenergy Im (i! n) at the low est M atsubara frequencies ! $n$ which gives $Z=(1 \quad @ \operatorname{Im}(i!)=@ i!)^{1}$ via the slope of the polynom inalat! = 0. T he resulting quasiparticle w eight for the $a_{1 g}$ - and the $e_{g}$ boands is show $n$ as a function of $U$ in $F$ ig. 14. W ith increasing $U, Z$ rst show sa strong decrease forboth types ofbands. H ow ever, in the vicinity of the M IT at about $\mathrm{U}=5 \mathrm{eV}$ the $\mathrm{a}_{1 \mathrm{~g}}$ quasiparticle weight rem ains constant while that of the $e_{g}$ electrons goes to zero. This behavior of the $a_{1 g}$ quasiparticle weight is in striking contrast to the behavior at the M IT in the oneband $H$ ubbard $m$ odelw here $Z!0$, such that its inverse, the e ective m ass, diverges. Indeed, from Fig. 14 alone one $m$ ight conclude that the M IT occurs only for the $e_{g}$ band. On the other hand, the total LD A + DM FT spectrum clearly show s insulating behavior at large C oulom b interactions.


FIG. 14: Q uasiparticle weight $Z$ for the $\mathrm{a}_{1 \mathrm{~g}}$ and the $\mathrm{e}_{\mathrm{g}}$ bands vs. $U$, using the crystal structure of $m$ etallic $\mathrm{V}_{2} \mathrm{O}_{3}$.

A quantity which $m$ easures the spectral weight at the Ferm ienergy and does not dependent on the analytical continuation to real frequencies is given by

$$
\begin{equation*}
-G(==2)=A \text { A }(!)-\frac{\exp (=2!)}{\left.\left\lvert\, \frac{1+\exp (\quad!)}{\{2}\right.\right\}} d!: \tag{4}
\end{equation*}
$$

M ore speci cally, $=G(==2) \mathrm{m}$ easures $\mathrm{A}(!)$ in the region given by the kemelK (!) which is centered around the Ferm ienergy at $!=0$ and has a w idth proportional
to $T=1=. T$ he results in $F$ ig. 15 show that, for 300 $K$, the spectral weight at the Ferm i energy disappears at a critical value of $U$ betw een $5: 1$ and $5: 2 \mathrm{eV}$ for both types of orbitals in the case ofm etallic $\mathrm{V}_{2} \mathrm{O}_{3}$. T hese values of $U$ agree quite wellw ith the position where the $e_{g}$ quasiparticle weight is expected to disappear in Fig .14. For the 300 K data for insulating $\left(\mathrm{V}_{0: 962} \mathrm{C} r_{0: 038}\right)_{2} \mathrm{O}_{3}$, the critical $U$-value is betw een $4: 9$ and $5: 0 \mathrm{eV}$. W ith increasing tem perature, the M IT is a sm eared out to becom e a crossover and, at 1160 K , is only signaled by a change of curvature slightly above 5 eV .

This analysis rea m s the correctness of our choice of the value $U=5 \mathrm{eV}$ for the sim ultaneous description of the $m$ etallic and insulating behavior of $\mathrm{V}_{2} \mathrm{O}_{3}$ and $\left(\mathrm{V}_{0: 962} \mathrm{C} r_{0: 038}\right)_{2} \mathrm{O}_{3}$, respectively.


FIG. 15: Spectral weight of the $\mathrm{a}_{1 \mathrm{~g}}$ and $\mathrm{e}_{\mathrm{g}}$ orbitals at the Ferm ienergy, as estim ated by $=G(==2)$, vs. $U$.

W e stillhave to address the question why the $a_{1 g}$ quasiparticle weight rem ains constant across the transition, i.e., why the e ective $a_{1 g} m$ ass does not diverge. The DMFT G reen function is given by Eq. (2) which under the assum ption of a Ferm i liquid-like self-energy

$$
\begin{equation*}
m(!)=\operatorname{Re}_{m}(0)+{\frac{@ \operatorname{Re}_{\mathrm{m}}(!)}{@!}}_{!=0}! \tag{5}
\end{equation*}
$$

and $Z=\left(1 \quad @ R e_{m}(!)=@!j=0\right)^{1} y$ ields

$$
\begin{equation*}
\left.G_{m}(!)=Z^{Z} \frac{Z N_{m}^{0}()}{!+Z\left(\operatorname{Re}_{m}(0)\right.}\right): \tag{6}
\end{equation*}
$$

Hence, an M IT can either occur if the e ective $m$ ass diverges, i.e., Z ! 0, or if the e ective chem ical potential $\operatorname{Re} m(0) \mathrm{m}$ oves, due to electronic correlations, outside the non-interacting LDA DOS such that $\mathrm{N}_{\mathrm{m}}^{0}(\operatorname{Re} \mathrm{~m}(0))=0$. In the case of $\mathrm{V}_{2} \mathrm{O}_{3}$ the latter happens as is dem onstrated by $F$ ig. 16, where Re m (0) hasbeen approxim ated by its value at the low est M atsubara frequency, $\left.\operatorname{Re} \mathrm{m}(!)_{0}\right)$. At the $\mathrm{M} I T$, betw een $\mathrm{U}=5: 1$ and 52 eV , $\operatorname{Re} a_{1 g}(0)$ crosses the upper LDA band edge while $\quad \operatorname{Re} e_{g}(0) \mathrm{m}$ oves below the lower band edge.

This explains the pronounced changes of the orbital occupation in Fig. 13 and, in particular, why an M IT can occur although the $\mathrm{a}_{1 \mathrm{~g}}$ quasiparticle weight does not vanish ( F ig. 14). This unexpected feature of the M IT has im portant physical consequences: Since at the M IT $\mathrm{N}_{\mathrm{a}_{1 g}}^{0}\left(\operatorname{Re} \mathrm{a}_{1 \mathrm{~g}}(0)\right)!0$, the height of the $\mathrm{a}_{1 g}$ quasiparticle peak goes to zero, rather than its width which is given by $Z$. For the $e_{g}$ band we have both $\mathrm{N}_{\mathrm{e}_{\mathrm{g}}}^{0}\left(\operatorname{Re} \mathrm{e}_{\mathrm{g}}(0)\right)!0$ and Z ! 0 such that height and width sim ultaneously go to zero. T herefore the quasiparticleDOSN ${ }_{a_{1 g}}^{0}\left(\operatorname{Re} a_{1 g}(0)\right)=Z$ does not diverge. C onsequently, physical quantities proportional to this quasiparticle D OS like the linear coe cient of the speci c heat and the local su sceptibility do not diverge, at least for the $\mathrm{a}_{1 \mathrm{~g}}$ bands.


FIG.16: E ective chem icalpotential Re (! o) vs.U.The upper and low er band edges of the non-interacting LD A D O S are shown as solid lines and the entire LDA DOS of $\mathrm{V}_{2} \mathrm{O}_{3}$ is plotted vertically at the right $z$-axis.
VI. COMPARISON W ITH EXPERIMENTAL SPECTRA

To be able to compare with experim ental photoem ission spectra the LDA + DMFT results were multiplied w ith the Ferm ifunction at the experim ental tem perature ( $\mathrm{T} \quad 180 \mathrm{~K}$ ) and broadened w ith a $0: 09 \mathrm{eV}$ G aussian to account for the experim ental resolution. ${ }^{28}$ The sam e procedure was used for the com parison w ith $x$-ray spectroscopy data (w ith an inverse Ferm i function at $T=300 \mathrm{~K}$ and a broadening of $0: 2 \mathrm{eV}$ taken from experim ent). On the experim ental side, the PES of Refs. 28,62 w ere corrected for the inelastic Shirley-type background which also rem oves the $02 p$ contribution. A 11 experim ental and theoretical curves were norm alized to yield the sam e area (w hich is a $m$ easure of the occupation of the vanadium $t_{2 g}$ bands).

In Fig . 17, LDA + DMFT results for tem peratures $1160 \mathrm{~K}, 700 \mathrm{~K}$, and 300 K are presented. Besides the broad, essentially tem perature independent peak at about $1: 25 \mathrm{eV}$ corresponding to the lower Hubbard band, the three curves clearly show the developm ent of a


FIG.17: LDA + D M FT (Q M C) results for the m etallic phase at di erent tem peratures.
well-de ned resonanœe-like structure just below the Ferm i energy when the tem perature is decreased. T he latter peak is what rem ains of the quasiparticle peak afterm ultiplication w ith the Ferm ifunction. At 1160 K it is nearly equal in height to the low er $H$ ubbard band, and there rem ains alm ost no m inim um betw een these two features.

In Fig. 18, the LD A + D M FT results at 300 K are com pared w th early photoem ission spectra by Schram $m e^{62}$ and recent high-resolution bulk-sensitive photoem ission spectra by MO et $\mathrm{al}^{28} \mathrm{~T}$ he strong di erence between the experim ental results is now known to be due to the distinct surface sensitivity of the earlier data. In fact, the photoem ission data by $\mathrm{M} \circ$ et $\mathrm{al}^{28}$ obtained at $\mathrm{h}=700 \mathrm{eV}$ and $\mathrm{T}=175 \mathrm{~K}$ exhibit, for the rst tim e , a pronounced quasiparticle peak. This is in good qualitative agreem ent w ith our low tem perature calculations. H ow ever, the experim ental quasiparticle peak has m ore spectralw eight. The origin for th is discrepancy, for a system as close to a M ott transition as $\mathrm{V}_{2} \mathrm{O}_{3}$, is presently not clear.


FIG. 18: C om parison of LDA + DMFT (QMC) results at $T=$ 300 K w ith photoem ission data by Schram meet al ${ }^{62}$ and M O et $\mathrm{al}^{28}$ for m etallic $\mathrm{V}_{2} \mathrm{O}_{3}$.

In $F$ ig. 19 we present the corresponding calculations for $\mathrm{C} r$-doped $\mathrm{V}_{2} \mathrm{O}_{3}$ : There is a lower Hubbard band
centered at about -1 eV as in the $m$ etallic phase, but a quasiparticle peak at the Ferm i energy no longer exists. It is interesting to note, how ever, that there rem ains som e spectral w eight in the vicinity of the Ferm ienergy. $C$ learly this is not a Ferm i liquid e ect, but is due to highly incoherent states w ith a large im aginary part of the low-frequency self-energy. W ith decreasing tem pera-


FIG. 19: Comparison of LDA and LDA + DMFT (QMC) results for insulating $\left(\mathrm{V}_{0: 962} \mathrm{Cr}_{0}: 038\right)_{2} \mathrm{O}_{3}$.
tures, th is incoherent spectralw eight is reduced and is expected to vanish for $T$ ! 0 . Therefore the resistance increases w ith decreasing tem perature as is to be expected for an insulator. For com parison we also show the LDA data in F ig. 19. T hey give a com pletely di erent picture: Besides a sm all peak at about $0: 8 \mathrm{eV}$ which is roughly in the sam e energy region as the low er H ubbard band of the LD A + DM FT calculations, it show s a strong peak slightly below the Ferm ienergy. C learly, LD A predicts a $m$ etallic solution, although the input crystalstructure is that for insulating $\left(\mathrm{V}_{0: 962} \mathrm{Cr}_{0}: 038\right)_{2} \mathrm{O}_{3}$.

W hile the com parison w th PES data provides im portant insight into the physics of $\mathrm{V}_{2} \mathrm{O}_{3}$, m ore than half of the theoretical spectrum lies above $\mathrm{E}_{\mathrm{F}}$. For this region we com pare our results at $1160 \mathrm{~K}, 700 \mathrm{~K}$, and 300 K w ith O 1s X -ray absorption spectra (XAS) for $\mathrm{V}_{2} \mathrm{O}_{3}$ at 300 K by M uller et al. ${ }^{63}$ (see Fig. 20). Since in the XA Sdata the Ferm i energy is not precisely determ ined, the data w ere shifted so that the peaks at 1:1 eV coincide; all curves w ere norm alized to the sam e area.
$T$ he theoretical spectra above $E_{F}$ are found to be alm ost independent of tem perature. Just above the Ferm i energy they all show som e structure (i.e., a shoulder at higher tem peratures developing into a sm all peak at low tem peratures ( 300 K )) which is the residue of the quasiparticle peak. Furtherm ore, at $1: 1 \mathrm{eV}$ there is a rather narrow peak, and at about $4: 2 \mathrm{eV}$ a broad peak. The latter tw o structures are parts of the upper $H$ ubbard band which is split due to the $H$ und's rule coupling $J$. H ence, the relative position of those tw o peaks can be expected to depend sensitively on the value of J. A slightly sm aller value of $J$ w ill therefore yield an even better agreem ent


FIG. 20: C om parison of LDA + DMFT (QMC) results w ith X ray absonption data by $M$ uller et $\mathrm{al}^{63}$ for m etallic $\mathrm{V}_{2} \mathrm{O}_{3}$.
w ith experim ent.
$T$ he absence of any quasiparticle w eight near $E_{F}$ in the XAS data is puzzling. This quasiparticle weight is not only present in the theoretical spectra above and below $\mathrm{E}_{\mathrm{F}}$, but is also seen in the high resolution PES measurem ents by $M$ o et $a l^{28}$ below $E_{F}$. This calls for additionalXA S or inverse photoem ission spectroscopy experim ents. For com parison w ith future experim ents, we also show the theoreticalX A S spectra for $C$ r-doped insulating $\mathrm{V}_{2} \mathrm{O}_{3}$ in F ig. 21, where our data have been broadened $w$ ith the experim ental resolution of $M$ uller et al. ${ }^{63}$


FIG. 21: LDA + DMFT (QMC) spectra for $E>E_{F}$ for insulating ( $\left.\mathrm{V}_{0: 962} \mathrm{C} r_{0: 038}\right)_{2} \mathrm{O}_{3}$.

The com parison betw een theoretical and experim ental spectra for $m$ etallic $\mathrm{V}_{2} \mathrm{O}_{3}$ is sum m ed up in F ig. 22 where our LDA + DM FT results for 300 K are shown together w ith the experim ental PES data by MO et $\mathrm{al}^{28}$ and XAS data by M uller et $\mathrm{al}^{63}$ To docum ent the theoretical im provem ent achieved by including the electronic correlations w th the LDA + DMFT technique we also show the results of LDA. W e note again that, by adjusting the value of $U$ such that the experim entally determ ined crystal structures lead to the correct $m$ etallic and insulating behavior, the spectrum was calculated $w$ ithout any further param eter $t$. In consideration of this fact the agreem ent of our results $w$ th the experi-
$m$ ental spectra above and below the Ferm ienergy is re$m$ arkably good. A though LD A yields the same gross


FIG. 22: C om parison of LDA + DMFT (QMC) results with PES data by M o et al ${ }^{28}$ and X -ray absonption data by M uller et $a l^{63}$ for the $m$ etallic phase above and below $E_{F}$
features, their weight, position and width neither agree w ith LDA + DMFT nor experim ent. The intenpretation of the tw o large peaks in the upper half of the spectrum is also di erent within LDA and LDA + DMFT.As denoted in the gure, the peaks in LDA are purely from $t_{2 g}$ (lower peak) and $e_{g}$ (upper peak) bands whereas they are $m$ ainly $a_{1 g}$ for the lower and $e_{g}$ for the upper peak in LDA + DMFT, w ith som e adm ixture of the respective other band.
$W$ e note that the $e_{g}$ bands were not taken into account in our calculations. T herefore, while the com plete LDA curve is norm alized to an area of 10 (corresponding to ten d-electrons), the experim ental and LDA + DM FT curves are norm alized to an area of 6 (corresponding to the six electrons of the $t_{2 g}$ bands). W em ay estim ate the position of the $e_{g}$ bands in a LD A + D M FT calculation as follow ing: A ssum ing that the intra $t_{2 g}$ C oulom $b$ interaction $V=U \quad 2 \mathrm{~J} \quad 3 \mathrm{eV}$ also applies for the interaction between spin-aligned $t_{2 g}$-and $e_{g}$-electrons, and taking the di erence betw een the $e_{g}$ - and $t_{2 g}$-band centers of gravIty of roughly $2: 5 \mathrm{eV}$ into account, we expect the $\mathrm{e}_{\mathrm{g}}-\mathrm{b}$ and to be located roughly at $2: 5 \mathrm{eV}+3 \mathrm{eV}=5: 5 \mathrm{eV}$ above the low er H ubbard band ( $-1: 5 \mathrm{eV}$ ), i.e., at about 4 eV . W ith this estim ate we expect the (upper) XAS peak at around 4 eV in Fig .22 to be an adm ixture of $e_{g}$ and $t_{2 g}$ states. $M$ ore precisely, this upper $H$ ubbard band describes transitions from $e_{g} e_{g}$ con gurations $w$ ith two electrons to the three-electron con gurations $e_{g} e_{g} e_{g}, e_{g} e_{g} a_{1 g}$, and $e_{g} e_{g} e_{g}$ (there is a m inor adm ixture of $e_{g} a_{1 g}$ states).

T he properties of param agnetic $\mathrm{V}_{2} \mathrm{O}_{3}$ across the M IT obtained w ith LD A + D M FT for a multitband m odel are thus found to be rem arkably di erent from those known from the one-band Hubbard model. Indeed, the orbital degrees of freedom are seen to play an essentialrole: They are not only responsible for the high asymm etry of the spectra below and above the Ferm i energy, but are also required to explain the reduction of the height of the quasiparticle peak at the Ferm ienergy w hen the M IT is approached in them etallic phase, as w ellas the sm allness
of the insulating gap.

## VII. CONCLUSION

U sing LDA -calculated densities of states for param agnetic $m$ etallic $\mathrm{V}_{2} \mathrm{O}_{3}$ as well as param agnetic insulating ( $\left.\mathrm{V}_{0: 962} \mathrm{C} r_{0}: 038\right)_{2} \mathrm{O}_{3}$ as input, we perform ed DMFT (Q M C ) calculations at $300 \mathrm{~K}, 700 \mathrm{~K}$, and 1160 K for various U values. For U 5 eV , the calculated spectra show a M ottHubbard M IT (or rather a shanp crossover at the tem peratures accessible by present-day QMC sim ulations). The details of this M IT are quite dierent from those obtained w thin the one-band H ubbard m odel ${ }^{13,15\{18}$ In the latterm odel the height of the quasiparticle peak at the Ferm ienergy is xed and the M IT is signaled by a divergence of the e ective $m$ ass (or the inverse quasiparticle weight $1=Z$ ) such that the width of the quasiparticle peak goes to zero. In contrast, our LDA + DMFT results show that, for the $\mathrm{a}_{1 g}$ quasiparticle peak, the height goes to zero while the width stays constant, as indicated by a roughly constant value of $1=\mathrm{Z}$ at the M IT . For the $e_{g}$ quasiparticle peak a com bination of, both, a reduced height and width at the M IT is found. $T$ his new type of physics, but also the high asym $m$ etry of the spectra below and above the Ferm ienergy as well as the sm allness of the insulating gap, are all due to the orbital degrees of freedom.

W e com pared our theoretical data at $\mathrm{U}=5 \mathrm{eV} \mathrm{w}$ ith the results of various experim ental $m$ easurem ents and found the orbital occupation to be predom inantly of $e_{g}$ character ( $w$ ith a sm all adm ixture of $a_{1 g}$ ) in agreem ent w ith experim ents. $T$ he occupation decreases for higher $U$-values, especially at low tem peratures. Furthem ore, we found a spin-1 state across the M IT in agreem ent w ith polarization dependent $X$ ray absonption $m$ easurem ents. $T$ he 300 K spectrum calculated by us form etallic $\mathrm{V}_{2} \mathrm{O}_{3}$ is in good overallagreem entw th new bulk-sensitive PES $m$ easurem ents. ${ }^{28}$ O $n$ the other hand, the di erence in the quasiparticle weight rem ains to be explained. The com parison $w$ th $X$-ray absonption $m$ easurem ents show $s$ that our LDA + DMFT (QMC) calculations also give a good description of the spectrum above the Ferm ienergy.

A ll calculations described above were done using the integral over the LDA density of states (DOS) (equation (2)) to obtain the lattice $G$ reen function. For a non-cubic system, this procedure is an approxim ation to the exact LDA + DMFT scheme. In the future we plan to $m$ ake use of the full $H$ am iltonian $H^{0}$ (eq. (1)). In this way it will be possible to study the in uence of correlation e ects on all orbitals including the $e_{g}$ orbitals and the oxygen states.
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${ }^{1}$ N. F. M ott, Rev. M od. Phys. 40, 677 (1968); M etalInsulator Transitions (T aylor \& Francis, London, 1990);
${ }^{2}$ F. Gebhard, The M ott M etal-Insulator Transition (Springer, Berlin, 1997).
${ }^{3}$ T.M.R ice and D.B.M CW han, IBM J.R es. D evelop. 14, 251 (1970).
${ }^{4}$ D. B.M CW han and J.P.Rem eika, Phys. Rev. B 2, 3734 (1970).
${ }^{5}$ D .B.M CW han, A .M enth, J.P.Rem eika, W .F .B rinkm an, and T.M.R ice, Phys. Rev.B 7, 1920 (1973).
${ }^{6}$ J. H ubbard, P roc. R oy. Soc. London A 276, 238 (1963).
${ }^{7}$ M . C. G utzw iller, P hys. Rev. Lett. 10, 59 (1963).
${ }^{8}$ J. K anam ori, P rog. Theor. P hys. 30, 275 (1963).
${ }^{9}$ J. H ubbard, P roc. R oy. Soc. London A 281, 401 (1964).
${ }^{10}$ W . F. B rinkm an and T. M . R ice, Phys. Rev. B 2, 4302 (1970).
${ }^{11}$ E.H.Lieb and F.Y.W u, Phys. Rev. Lett. 20, 1445-1448 (1968).
${ }^{12}$ W . M etzner and D . Vollhardt, Phys. Rev. Lett. 62, 324 (1989).
${ }^{13}$ A. G eorges, G. K otliar, W . K rauth, and M . J. R ozenberg, Rev.M od. Phys. 68, 13 (1996).
${ }^{14}$ W . F. Brinkm an and T.M.Rice, Phys. Rev. B 2, 4302 (1970).
${ }^{15}$ G . M oeller, Q. Si, G . K otliar, M . J. R ozenberg, and D . S. F isher, Phys. Rev. Lett. 74, 2082 (1995).
${ }^{16}$ M . J. R ozenberg, R. Chitra and G. K otliar, Phys. Rev. Lett. 83, 3498 (1999).
${ }^{17}$ R. Bulla, P hys. Rev. Lett. 83, 136 (1999).
${ }^{18} \mathrm{M}$. J. R ozenberg, G . K otliar, H . K a jueter, G . A . Thom as, D. H. R apkine, J. M . H onig, and P.M etcalf, Phys. Rev. Lett. 75,105 (1995).
${ }^{19}$ M . J. R ozenberg, Phys. R ev.B 55, R 4855 (1997).
${ }^{20}$ J. E. Han, M . Jarrell, and D. L. C ox, Phys. Rev. B 58, R 4199 (1998).
${ }^{21}$ K.Held and D.Vollhardt, Euro.Phys.J.B 5, 473 (1998).
${ }^{22}$ P. Lim elette, A. G eorges, D. Jerom e, P. W zietek, P. M etcalf, J. M . H on ig, Science 302, 89 (2003).
${ }^{23}$ G. K otliar, Eur. J. Phys. B 11, 27 (1999).
${ }^{24}$ G. K otliar, E. Lange, M . J. R ozenberg, Phys. Rev. Lett. 84,5180 (2000).
${ }^{25}$ K . H eld, G . K eller, V .E yert, V . I. A n isim ov, D .V ollhardt, Phys. Rev.Lett. 86, 5345 (2001).
${ }^{26}$ V. I. A nisim ov, A. I. Poteryaev, M. A. K orotin, A. O . A nokh in, and G. K otliar, J. Phys. C ond. M atter 9, 7359 (1997); A. I. Lichtenstein and M .I.K atsnelson, P hys. Rev. B 57, 6884 (1998).
${ }^{27}$ K . H eld, I. A . N ekrasov, G . K eller, V . E yert, N. B lum er, A K. M OM ahan, R.T. Scalettar, Th. P ruschke, V .I. A nisim ov und D. Vollhardt, \Realistic investigations of correlated electron system s with LDA + DMFT", Psi-k N ew sletter \# 56, 65 (2003)
[http://psi-k.dlac.uk/new sletters/ N ew s_56/H igh light_56.pdf] .
${ }^{28}$ S.K.M O, J.D.D enlinger, H.-D.K im, J.H. P ark, J.W . A llen, A. Sekiyam a, A. Y am asaki, K . K adono, S. Suga, Y.

Saitoh, T.M uro, P.M etcalf, G . K eller, K . H eld, V .E yert, V.I. A nisim ov, D.V ollhardt, P hys. R ev. Lett. 90, 186403 (2003).
${ }^{29}$ P.D.D em ier, J. P hys. C hem . Solids 31, 2569 (1970).
${ }^{30}$ L.F.M attheiss, J. Phys.: C ond.M att. 6, 6477 (1994).
${ }^{31}$ P. H ohenberg and W . K ohn, Phys. Rev.136, B 864 (1964).
${ }^{32}$ W . K ohn and L. J. Sham, Phys. Rev. 140, A 1133 (1965).
${ }^{33}$ A.R.W illiam S, J. K ubler, and C.D.G elatt, Jr., Phys. Rev.B 19, 6094 (1979).
${ }^{34} \mathrm{~V}$. E yert, Int. J. Q uantum C hem . 77, 1007 (2000).
5 J.W . A llen, Phys. Rev. Lett. 36, 1249 (1976).
${ }^{36}$ C . C astellani, C.R.N atoli, and J. R anninger, P hys. R ev. B 18, 4945 (1978), ibid. 18, 4967 (1978), ibid. 18, 5001 (1978).

37 J.H. Park et al, Phys. Rev.B 61, 11506 (2000).
${ }^{38}$ S. Yu.Ezhov, V. I. A nisim ov, D. I. K hom skii, and G.A. Saw atzky, Phys. Rev. Lett. 83, 4136 (1999).
${ }^{39}$ F.M ila, R .Shina, F.C. Zhang, A . Joshi, M .M a, V .A nisim ov, T.M.R ice, P hys R ev. Lett. 85, 1714 (2000).
${ }^{40}$ A. Tanaka, J. Phys. Soc. Japan, 71, 1091, 2002.
${ }^{41}$ S.D iM atteo, N.B. P erk ins, and C . R . N atoli, Phys. R ev. B 65, 054413 (2002).
${ }^{42}$ I. S. Elm ov, T. Saha-D asgupta, M. A. K orotin, condm at/0303404
${ }^{43}$ L. Hedin and B. Lundqvist, J. Phys. C : Solid State Phys. 4, 2064 (1971); U. von B arth and L. Hedin, J. Phys. C : Solid State P hys. 5, 1629 (1972).
${ }^{44}$ D . M . C eperley and B . J. A lder, P hys. Rev. Lett. 45, 566 (1980).
${ }^{45}$ R . Bulla, T. A . C osti, D . Volh hardt, Phys. Rev. B 64, 045103 (2001).
${ }^{46}$ V.I.A nisim ov, J. Z aanen, and O.K.A ndersen, Phys. R ev. B 44,943 (1991); V.I.A nisim ov, F.A ryasetiaw an, and A. I. Lichten stein, J. P hys. C ond. M atter 9, 767 (1997).
${ }^{47} \mathrm{M} . \mathrm{Zol}, \mathrm{Ph} D$. thesis, U niversitat R egensburg, 2001.
${ }^{48}$ I. Solovyev, N. H am ada, K . Terakura, Phys. Rev. B 53, 7158 (1996).
${ }^{49}$ I. A . N ekrasov, K . H eld, N . B hum er, V . I. A nisim ov, and D. Vollhardt, Euro. Phys. J. B 18, 55 (2000).
${ }^{50}$ For the $t_{2 g}$ partialD O S'swe disregarded the sm all $t_{2 g}$ contributions to the oxygen bands (in the range -9 to -4 eV ) and renorm alized the D O S's to unity. T h is resem bles m ost closely the DOS's which one would obtain if one downfolded the LDA bandstructure to an e ective three-band H am iltonian at the Ferm ienergy.
${ }^{51}$ See, e.g., A. Liebsch and A. Lichtenstein, P hys. R ev. Lett. 84,1591 (2000); I.A.N ekrasov, Z.V.P chelkina, G .K eller, Th. P ruschke, K . Held, A . K rim m el, D . Vollhardt, V. I. A nisim ov, Phys. Rev. B 67, 085111 (2003); L. C raco, M . S. Laad, and E. M ullerH artm ann, Phys. Rev. Lett. 91 156402 (2003); A. Sekiyam a, H. Fu jiv ara, S. Im ada, S. Suga, H.E isaki, S. I. U chida, K . Takegahara, H . H arim a, Y . Saitoh, I. A . N ekrasov, G . K eller, D . E . K ondakov, A . V.K ozhevnikov, Th.P ruschke, K .H eld, D.Vollhardt, and V. I. A nishim ov, cond-m at/0312429; E. P avarini, S.B ier-
m ann, A . P oteryaev, A. I. Lichten stein, A. G eorges, O . K . A ndersen, and cond-m at/0309102.
52 See, e.g., A. I. Lichtenstein, M . I. K atsnelson, and G. K otliar 87, 67205 (2001); S. B ierm ann, A. D alm eyer, C . C arbone, W. Eberhardt, C. Pam puch, O. R ader, M.I. $K$ atsnelson, and A. I. Lichtenstein, cond-m at/0112430.
53 See, e.g., S.Y. Savrasov, G . K otliar, and E.Abraham s, N ature 410, 793 (2001); M . B. Zol, I. A . N ekrasov, Th. P ruschke, V. I. A nisim ov, and J. K eller, P hys. R ev. Lett. 87,276403 (2001); K . H eld, A. K . M CM ahan, and R . T. Scalettar P hys. R ev.Lett. 87, 276404 (2001); A.K .M dM ahan, K .H eld, and R.T.Scalettar P hys. R ev.B 67, 075108 (2003).

54 J. E. H irsch and R.M.Fye, Phys. Rev. Lett. 56, 2521 (1986); M . Jarrell, Phys. Rev. Lett. 69, 168 (1992); M . R ozenberg, X . Y . Zhang, and G.K otliar, P hys. R ev. Lett. 69,1236 (1992); A. G eorges and W . K rauth, Phys. R ev. Lett. 69, 1240 (1992); M . Jarrell, in N um erical M ethods for Lattioe $Q$ uantum $M$ any-B ody $P$ roblem $s$, edited by $D$. Scalapino (A ddison $W$ esley, $N$ ew -Y ork, 1997).
${ }^{55}$ M . U Im ke, V. Janis, and D.Vollhardt, Phys. R ev. B 51, 10411 (1995).
${ }^{56}$ M. Jarrell and J. E. G ubematis, Physics Reports 269,

133 (1996).
57 A. T. M izokaw a, A. Fu ̈̈m ori, Phys. Rev. B 48, 14150 (1993); J. Zaanen, G . A . Saw atzky, J. Solid State C hem . 88, 8 (1990).
${ }^{58}$ A. C. H ew son $T$ he $K$ ondo P roblem to $H$ eavy Ferm ions (C am bridge U niversity P ress, C am bridge, 1993).
59 For us to recover the picture of C astellaniet al ${ }^{36}$ not only an unrealistically $s m$ all value of $J$ would be required, but the LD A result would also have to be di erent. N am ely, a splitting of the $\mathrm{a}_{1 \mathrm{~g}}$ orbital into a binding and antibinding peak of equal weight would be necessary to obtain an $a_{1 g}$ singlet $w$ ith occupation $n_{a_{1 g}}=1$, leaving an unpaired spin $s=1=2$ in the $e_{g}$ orbitals.
${ }^{60}$ D. J.A mold, R . W .M ires, J. C hem .P hys. 48, 2231 (1968)
${ }^{61}$ P. J. B rown, M . M . R . C osta, K . R . A . Z iebeck, J. P hys.: C ond. M atter 10, 9581 (1998).
${ }^{62}$ M . Schram m e, Ph.D. thesis, U niversitat A ugsburg, 2000; M. Schram $m$ e et al. (unpublished).
${ }^{63}$ O.M uller, J.P.U noach, E. G oering, T.W eber, R . B arth, H. Schuler, M. K lem m, and S. H om, Phys. Rev. B 56, 15056 (1997).

